Monolithic Digital IC



NO.535C

LB1274

6-Unit, Darlington Transistor Array

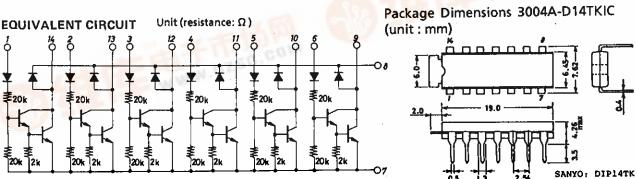
Circuit structure of this IC is a 6-unit Darlington transistor array with NPN transistors. The IC is ideal for driving printers, relays, and lamps. Protective diodes guard against negative inputs. Thus it has advantages when designing circuits to drive printer-calculators that use display tubes, cash registers, and the like.

FEATURES

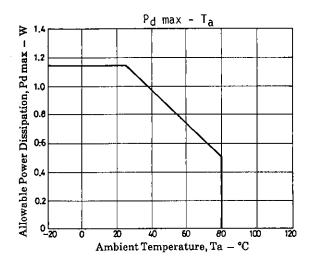
- Ideal for 18-digit printers (because it has 6 units.)
- Protective diodes are incorporated against negative inputs (V_{IN} = -40 ~ +20 V).
- Ideal for printers, with 85-mA load current (IOUT max = 100 mA DC).
- Spark-killer diodes accommodate L-loads.

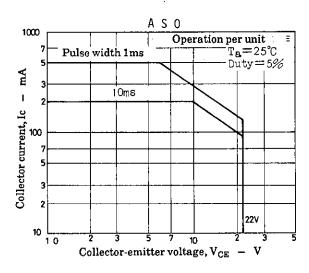
Α	BSOLUTE MAXIMUM RATINGS/Ta =	= 25°C			unit	
	Output supply voltage	Vout		$-0.3 \sim +22$	V	
	Input supply voltage	VIN		−40 ~ +20	V	
	Pin-8 supply voltage	٧8		−0.3 ~ +20		
	Output inflow current	IOUT	Per unit	0 ~ 100	mΑ	
	Instantaneous output inflow current	IOP	Per unit: duty $\leq 10\%$ Pulse width < 20 ms	0 ~ 150	mΑ	
	Spark killer diode forward current	IF(s)	Per diode: duty $\leq 10\%$ Pulse width < 20 ms	0 ∼ 150	mA	
	GND-pin outflow current	17		−700 ~ 0	mΑ	
	Pin-8 instantaneous outflow current	18p	duty \leq 10%, Pulse width \leq 20 ms	−500 ~ 0	mA	
	Allowable power dissipation	P _d max		1,15	W	
	Junction temperature	Τį		125	°C	
	Operating ambient temperature	Topr		–20 ∼ +80	°C	
	Storage ambient temperature	T _{stg}		−40 ~ +125	°C	

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ALLOWABLE OPERATING CO	NDITIONS/Ta	= 25°C, pin 7 = 0 V		unit
Output supply voltage	Vout		22	V or less
Input high-level voltage	VIH	Output terminal current = 100 mA	9 ~ 20	V
Input low-level voltage	VIL	Output terminal current = 100 μ A	−35 ~ +1	V
Load inductance	LL	Protective diodes employed	100	mH or less



ELECTRICAL CHARACTERISTICS/T	a = 25°C, pin	7 = 0 V	min	typ	max	unit
Output voltage	Vout(1)	$V_{IN} = 9.0 V, I_{OUT} = 150 mA$			1.7	V
	VOUT(2)	$V_{IN} = 9.0 V$, $I_{OUT} = 100 mA$			1.4	V
Output sustaining voltage	VOUT(s)	V_{1N} = open, I_{OUT} = 150 mA Applied time < 10 μ s	22			٧
Output leakage current	loff	V _{IN} = 1.0 V, V _{OUT} = 22 V			100	μΑ
Input current	^I IN(1)	V _{IN} = 18 V			1.8	mΑ
	[[] IN(2)	V _{IN} = 9.0 V			8.0	mΑ
Output current	IOUT	$I_{1N} = 0.3 \text{ mA, V}_{OUT} = 1.4 \text{ V}$	100			mΑ
Input leakage current	lleak	V _{IN} =35 V	-10			μΑ
Spark killer diode leakage current	lleak(s)	$V_{OUT} = 0 V$, pin 8 = 20 V			30	μΑ
Spark killer diode forward voltage	VF(s)	IF(s) = 150 mA			1.7	V





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